

FORM PTO-1449
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09/697,203

INFORMATION DISCLOSURE CITATION

(Use several sheets if necessary)

Applicant

Kozlowski, Lester J..

Filing Date

October 26, 2000

Group

2878

U.S. PATENT DOCUMENTS

*Examine r Initials		Document Number	Date	Name	Class	Subclass	Filing Date
if	AA	Re 34,908	9/5/00	Wyles, et al			
if	AB	4,249,122	2/3/81	Widlar			
if	AC	4,463,383	7/31/84	Sonoda, et al			
if	AD	4,466,018	8/14/84	Sonoda, et al			
if	AE	4,676,761	6/30/87	Poujois			
if	AF	4,794,247	12/27/88	Stineman, et al			
if	AG	5,043,820	8/27/91	Wyles, et al			
if	AH	5,083,016	1/21/92	Wyles, et al			
if	AI	5,345,266	9/6/94	Denyer, et al			
if	AJ	5,296,696	3/22/94	Uno, M.			
if	AK	5,471,515	11/28/95	Fossum, et al			
if	AL	5,576,763	11/19/96	Ackland, et al			
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if	AN	5,587,596	12/24/96	Chi, et al			
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if	AP	5,055,667	10/08/91	Sayag			
if	AQ	5,128,534	7/7/92	Wyles, et al			
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if	AS	5,382,977	1/17/95	Kozlowski, et al			
if	AT	5,627,112	5/6/97	Tennant, et al			
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if	AX	6,064,431	5/16/00	Ueno			
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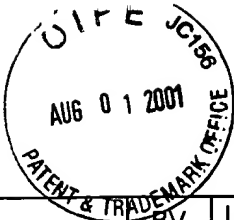
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y.	BD	J.D. Plummer and J.D. Meindl, "MOS Electronics For A portable Reading Aid For The Blind", IEEE J. Solid-State Circuits, SC-7, April 1972, pp. 111-119
y.	BE	N. Koikka, I. Takemoto, K. Satoh, S. Hanamura, S. Nagahara and M. Kubo, "MOS Area Sensor: Part I - Design Consideration And Performance Of An n-p-n Structure 484 x 384 Element Color MOS Imager", IEEE Trans Electron Devices, ED-27 (8), August 1980, pp. 1676-1681
y.	BF	S. Ohba, M. Nakai, H. Ando, S. Hanamura, S. Shimada, K. Satoh, K. Takahashi, M. Kubo and T. Fujita, "MOS Area Sensor: Part II - Low-Noise MOS Area Sensor With Antiblooming Photodiodes", IEEE Trans. Electron Devices, ED-27 (8) August 1980, pp. 1682-1687
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y.	BI	EG&G Reticon Sales Catalog, Image Sensing and Solid State Camera Products 1994/1995. Solid State Sensor Arrays Specification For Part Nos: RA0100A/RA0128N
y?	BJ	H. Ando, S. Ohba, M. Nakai, T. Ozaki, M. Ozawa, K. Ikeda, T. Masuhara, T. Imaide, I. Takemoto, T. Suzuki and T. Fukita, "Design Consideration And Performance Of A New MOS Imaging Device", IEEE Trans. On Elec. Dev., ED-32 (8), August 1985, pp. 1484-1489
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y.	BM	N. Tanaka, T. Ohmi, Y. Nakamura and S. Matsumoto, "A Low-Noise Bi-CMOS Linear Imager Sensor With Auto-Focusing Function", IEEE Trans. Elec. Dev., 36 (1), January 1989, pp. 39-45
y.	BN	N. Tanaka, S. Hashimoto, M. Shinohara, S. Sugawa, m. Morishita, S. Matsumora, Y. Nakamura and T. Ohmi, "A 310k Pixel Bipolar Imager (BASIS), ISSCC 1989
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y.	BR	L.J. Kozlowski, J. Luo, W.E. Kleinhans and T. Lui, "Comparison Of Passive And Active Pixel Schemes For CMOS Visible Imagers", SPIE, Vol. 3360, April 1998
y.	BS	Ming-Jer Chin, Yen-Bin Gu, Terry Wu, Po-Chin Hsu and Tsung-Hann Liu, "Weak Inversion Charge Injection In Analog MOS Switches", IEEE Journal Of Solid-State Circuits, Vol. 30, No. 5, May 1995, pp. 604-606
y.	BT	Peter W. Fry, Peter J. W. Noble and Robert J. Rycroft, "Fixed-Pattern Noise In Photomatrices", IEEE Journal Of Solid-State Circuits, Vol. SC-5, No. 5, October 1970, pp. 250-254
y.	BU	Degrauwe, et al., "A Micropower CMOS-Instrumentation Amplifier", IEEE Journal Of Solid-State Circuits, Vol. SC-20, No. 3 June 1985, pp. 805-807

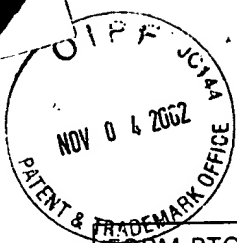


uf.	BV	Letter Dated July 31, 1998, From Gene Weckler, RAD-ICON IMAGING CORP., addressed to Mark Wettler
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uf.	BY	Mendis, et al., "A 128 x 128 CMOS Active Pixel Image Sensor For Highly Integrated Imaging Systems," IEEE Electron Device Meeting, p. 583, 1993
Examiner 		Date Considered 3/19/04
*Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw Line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.		

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*Examine Initials		Document Number	Date	Name	Class	Subclass	Filing Date
ly	AA	6,243,134	06/05/01	Beiley			02/27/98
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FOREIGN PATENT DOCUMENTS							
		Document Number	Date	Country	Class	Subclass	Translation Yes No
OTHER PRIOR ART (Including Author, Title, Date, Pertinent Pages, Etc.)							
ly	AB	Copy of International Search Report					
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